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## 30V N-Channel PowerTrench<sup>o</sup> MOSFET

### **General Description**

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low  $R_{DS(ON)}$ , fast switching speed and extremely low  $R_{DS(ON)}$  in a small package.

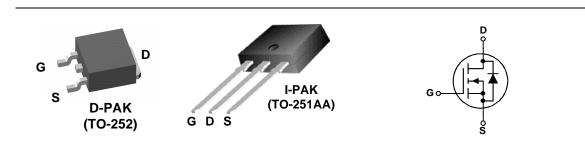
### Applications

- DC/DC converter
- Motor Drives

### Features

• 30 A, 30 V 
$$R_{DS(ON)} = 20 \ m\Omega \ @ V_{GS} = 10 \ V$$
  
 $R_{DS(ON)} = 28 \ m\Omega \ @ V_{GS} = 4.5 \ V$ 

- Low gate charge
- Fast Switching
- High performance trench technology for extremely low R<sub>DS(ON)</sub>



### Absolute Maximum Ratings T<sub>A</sub>=25°C unless otherwise noted

Symbol	Para	meter		Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage			30	V
V <sub>GSS</sub>	Gate-Source Voltage			±20	V
ID	Continuous Drain Current	@T <sub>c</sub> =25°C	(Note 3)	30	A
		@T <sub>A</sub> =25°C	(Note 1a)	9.5	
		Pulsed	(Note 1a)	60	
P <sub>D</sub>	Power Dissipation	@T <sub>c</sub> =25°C	(Note 1)	36	W
		@T <sub>A</sub> =25°C	(Note 1a)	2.8	
		@T <sub>A</sub> =25°C	(Note 1b)	1.3	
$T_J, T_STG$	Operating and Storage Ju	nction Tempera	ture Range	-55 to +175	°C
Therma	I Characteristics				
$R_{ ext{ heta}JC}$	Thermal Resistance, Junc	tion-to-Case	(Note 1)	3.9	°C/W

$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	3.9	°C/VV
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	45	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1b)	96	°C/W

### Package Marking and Ordering Information

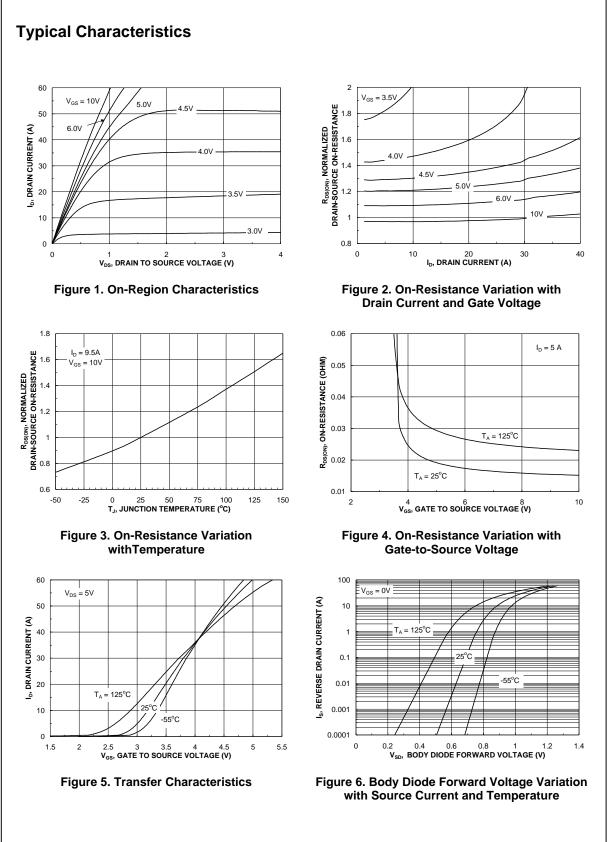
Device Marking	Device	Package	Reel Size	Tape width	Quantity
FDD6612A	FDD6612A	D-PAK (TO-252)	13"	16mm	2500 units
FDU6612A	FDU6612A	I-PAK (TO-251)	Tube	N/A	75

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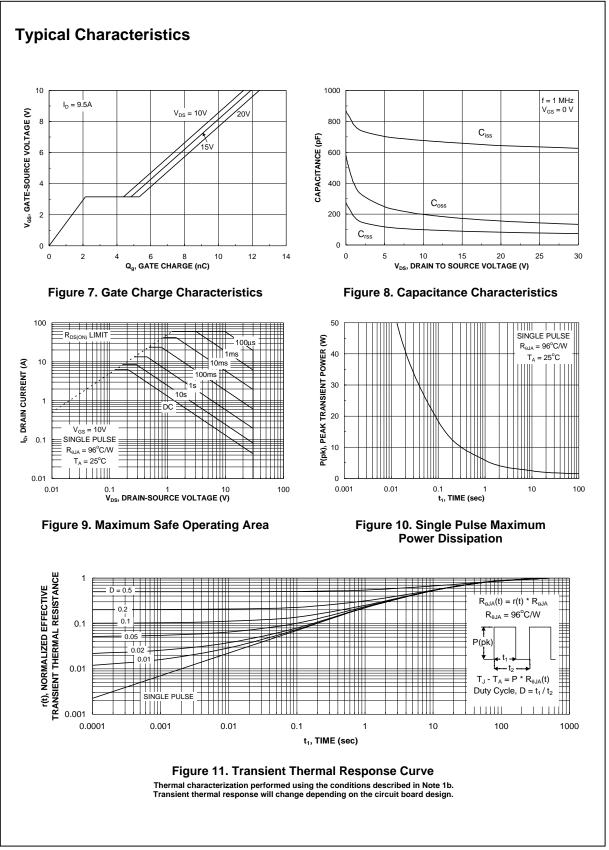
# March 2015

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-So	ource Avalanche Ratings (Not	e 2)				
W <sub>DSS</sub>	Drain-Source Avalanche Energy	Single Pulse, $V_{DD} = 27 \text{ V}$ , $I_D = 10 \text{ A}$			51	mJ
I <sub>AR</sub>	Drain-Source Avalanche Current				10	Α
Off Char	acteristics	· · · · ·		•	•	•
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 V$ , $I_D = 250 \mu A$	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A,Referenced to $25^{\circ}$ C		25		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V},  V_{GS} = 0 \text{ V}$			1	μA
I <sub>GSS</sub>	Gate-Body Leakage	$V_{GS} = \pm 20 \text{ V},  V_{DS} = 0 \text{ V}$			±100	nA
On Char	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	1	2.0	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A,Referenced to $25^{\circ}$ C		-5.1		mV/°C
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance	$ \begin{array}{ll} V_{GS} = 10 \; V, & I_D = 9.5 \; A \\ V_{GS} = 4.5 \; V, & I_D = 8 \; A \\ V_{GS} = 10 \; V, & I_D = 9.5 \; A, \; T_J \!=\! 125^\circ \! C \end{array} $		15 20 23	20 28 33	mΩ
<b>g</b> fs	Forward Transconductance	$V_{DS} = 5 V$ , $I_D = 9.5 A$		28		S
Dvnamio	Characteristics		•			
C <sub>iss</sub>	Input Capacitance			660		pF
Coss	Output Capacitance	$V_{DS} = 15 \text{ V},  V_{GS} = 0 \text{ V},$		170		pF
Crss	Reverse Transfer Capacitance	f = 1.0 MHz		90		pF
R <sub>G</sub>	Gate Resistance	V <sub>GS</sub> = 15 Mv, f = 1.0 MHz		2.3		Ω
Switchin	g Characteristics (Note 2)					
t <sub>d(on)</sub>	Turn–On Delay Time			9	18	ns
t <sub>r</sub>	Turn–On Rise Time	$V_{DD} = 15 V, I_D = 1 A,$		5	10	ns
t <sub>d(off)</sub>	Turn–Off Delay Time	$V_{GS} = 10 V$ , $R_{GEN} = 6 \Omega$		24	38	ns
t <sub>f</sub>	Turn–Off Fall Time			4	8	ns
Q <sub>g</sub>	Total Gate Charge			6.7	9.4	nC
Q <sub>gs</sub>	Gate-Source Charge	$V_{DS} = 15 V$ , $I_D = 9.5 A$ , $V_{GS} = 5 V$		2.1		nC
Q <sub>gd</sub>	Gate-Drain Charge	VGS = 5 V		2.7		nC

<u> </u>	Parameter	Test Conditions	Min	Тур	Max	Units
Drain–So	Durce Diode Characteristics	s and Maximum Ratings				
ls	Maximum Continuous Drain–Source				2.3	А
V <sub>SD</sub>	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V, I_S = 2.3 A$ (Note 2)		0.8	1.2	V
rr	Diode Reverse Recovery Time	IF = 9.5 A, diF/dt = 100 A/µs		20		nS
Qrr	Diode Reverse Recovery Charge			10		nC
	a) $R_{eJA} = 45^{\circ}C/$ $1in^2$ pad of 2	W when mounted on a		_= 96°C/W minimum	when mou pad.	nted
Scale 1 : 1 on I	etter size paper					
	lse Width < 300μs, Duty Cycle < 2.0%					
Maximum curr	rent is calculated as: $\sqrt{\frac{P_D}{R_{DS(ON)}}}$					
where P <sub>D</sub> is m	aximum power dissipation at $T_{C} = 25^{\circ}C$ and $R_{DS}$	$T_{J(max)}$ is at $T_{J(max)}$ and $V_{GS} = 10V$ . Package current	limitation is 2	21A		



FDD6612A/FDU6612A Rev. 4.1



FDD6612A/FDU6612A Rev. 4.1



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